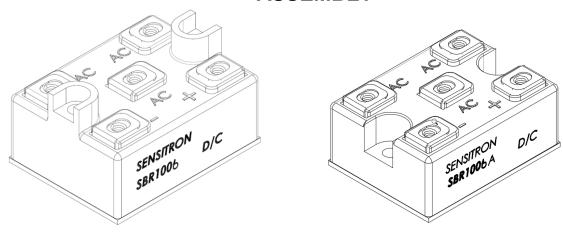


TECHNICAL DATA DATA SHEET 5481, REV. C

# THREE PHASE FULL WAVE BRIDGE FAST-RECTIFIER ASSEMBLY



DESCRIPTION: 1000 V, 100 A THREE PHASE BRIDGE RECTIFIER ASSEMBLY WITH FAST RECTIFIERS. REDUCED EMI - LOW  $t_{\rm RR}$  AND  $l_{\rm RM}$ .

MAX. RATINGS / ELECTRICAL CHARACTERISTICS All ratings are at  $T_A = 25^{\circ}$ C unless otherwise specified.

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Non-Repetitive Peak Inverse Voltage (PIV)	$T_C = 25$ °C	1	-	1200	Vdc
Repetitive Peak Inverse Voltage (PIV)	$T_{\rm C} = -55^{\circ}{\rm C}$ to $150^{\circ}{\rm C}$	1	-	1000	Vdc
Average DC Output Current	$T_C = 55$ °C	-	-	190	А
$(T_C = Case Temp) (I_o)$	T <sub>C</sub> = 100 °C			100	
Peak Single Cycle Surge Current (I <sub>FSM</sub> )	$t_p = 8.3 \text{ ms Single Sine}$ wave $T_C = 25 ^{\circ}\text{C}$	1500	-	-	А
Single Cycle Energy Rating	$t_p$ = 8.3 ms Single Sine wave $T_C$ = 25 °C	1	9300	-	A <sup>2</sup> s
Operating and Storage Temp (T <sub>op</sub> & T <sub>stq</sub> )	-	-55	-	+150	°C
Junction Temp (T <sub>J</sub> )	-	-55	-	+190	°C
Maximum Forward Voltage (V <sub>f</sub> ) (300 μsec pulse, duty cycle < 2%)	$T_C = 25$ °C, $I_f = 100$ A	-	-	1.25	V
	$T_C = 125$ °C, $I_f = 100$ A			1.20	
Maximum Instantaneous Reverse Current At 1000V	T <sub>C</sub> = 25° C	-	-	50	μΑ
	T <sub>C</sub> = 100° C			4000	
Reverse Recovery Time	$I_F = 40A$ , $V_R = 100V$ , di/dt = 25A/ $\mu$ s, $T_C = 25^0$ C	0.6	-	2.0	μs

## **SENSITRON**

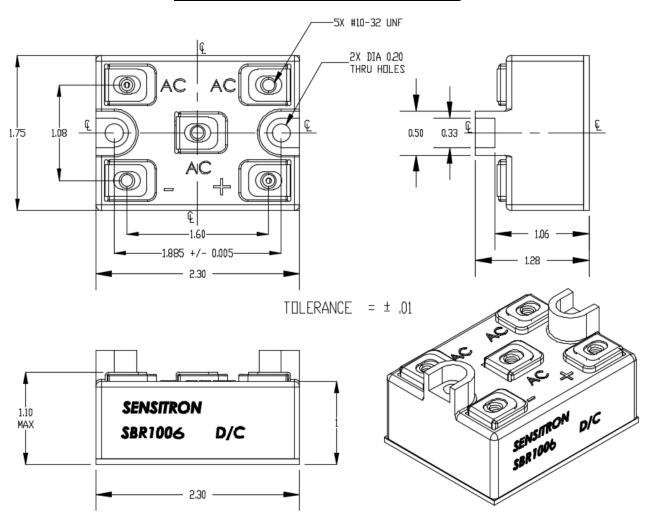
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### **Mechanical / Thermal Characteristics:**

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Isolation Voltage	All Terminals - Base Plate	-	-	1500	VRMS
Mounting Torque	-	-	-	30	In-lb.
Weight	-	-	-	155	gms
Thermal Resistance (θ <sub>JL</sub> )	Per Diode	-	-	0.40	°C/W

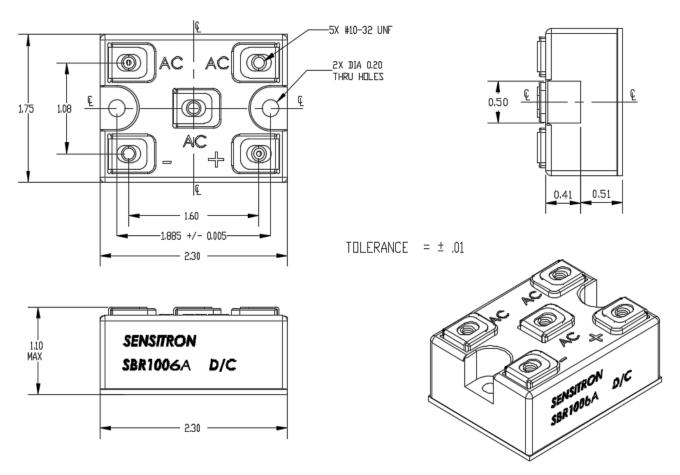
Note: Add a suffix **S** to the part number for S-100 Screening.

## **MECHANICAL DIMENSIONS: In Inches**



PKG:C1BM1-5T

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PKG:C1BM1-5T

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